NSN 5961-00-829-6994

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View Online at https://aerobasegroup.com/nsn/5961-00-829-6994 **Overall Height:** 0.160 inches **Overall Diameter:** 0.335 inches **Component Name And Quantity:** 2 transistor **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 50.0 breakdown voltage, collector-to-emitter, base open all transistor and 75.0 breakdown voltage, collector-to-base, emitter open all transistor and 7.0 emitter to base voltage, static, collector open all transistor **Current Rating Per Characteristic:** 500.00 milliamperes source cutoff current all transistor **Power Rating Per Characteristic:** 450.0 milliwatts small-signal input power, common-collector all transistor **Special Features:** Internal junction configuration transistor npn Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: